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June 2014

FGY75N60SMD

600 V, 75 A Field Stop IGBT

Features

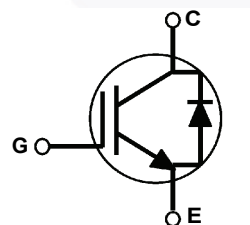
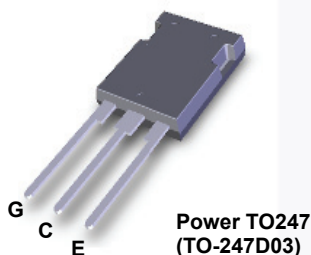
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.9 \text{ V @ } I_C = 75 \text{ A}$
- High Input Impedance
- Fast Switching : $E_{OFF} = 10 \text{ uJ/A}$
- RoHS Compliant

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2nd generation IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.

Application

- Solar Inverter, UPS, Welder, SMPS, PFC



Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
V_{CES}	Collector to Emitter Voltage	600	V
V_{GES}	Gate to Emitter Voltage	± 20	V
	Transient Gate to Emitter Voltage	± 30	V
I_C	Collector Current @ $T_C = 25^\circ\text{C}$	150	A
	Collector Current @ $T_C = 100^\circ\text{C}$	75	A
$I_{CM(1)}$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	225	A
I_F	Diode Forward Current @ $T_C = 25^\circ\text{C}$	75	A
	Diode Forward Current @ $T_C = 100^\circ\text{C}$	50	A
$I_{FM(1)}$	Pulsed Diode Maximum Forward Current	225	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	750	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	375	W
T_J	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
T_L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature.

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.2	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case	-	0.48	$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	$^{\circ}\text{C}/\text{W}$

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGY75N60SMD	FGY75N60SMD	TO-247D03	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	600	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_J}$	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	-	0.67	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0 V	-	-	±400	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	3.5	5.0	6.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 75 A, V _{GE} = 15 V	-	1.90	2.50	V
		I _C = 75 A, V _{GE} = 15 V, T _C = 175°C	-	2.14	-	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	-	3800	-	pF
C _{oes}	Output Capacitance		-	390	-	pF
C _{res}	Reverse Transfer Capacitance		-	105	-	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 75 A, R _G = 3 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25°C	-	24	32	ns
t _r	Rise Time		-	56	73	ns
t _{d(off)}	Turn-Off Delay Time		-	136	177	ns
t _f	Fall Time		-	22	29	ns
E _{on}	Turn-On Switching Loss		-	2.3	2.99	mJ
E _{off}	Turn-Off Switching Loss		-	0.77	1.00	mJ
E _{ts}	Total Switching Loss		-	3.07	3.99	mJ
t _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 75 A, R _G = 3 Ω, V _{GE} = 15 V, Inductive Load, T _C = 175°C	-	23	-	ns
t _r	Rise Time		-	53	-	ns
t _{d(off)}	Turn-Off Delay Time		-	146	-	ns
t _f	Fall Time		-	15	-	ns
E _{on}	Turn-On Switching Loss		-	3.60	-	mJ
E _{off}	Turn-Off Switching Loss		-	1.11	-	mJ
E _{ts}	Total Switching Loss		-	4.71	-	mJ

Electrical Characteristics of the IGBT $T_C = 25^\circ\text{C}$ unless otherwise noted

Q_g	Total Gate Charge	$V_{CE} = 400\text{ V}, I_C = 75\text{ A},$ $V_{GE} = 15\text{ V}$	-	248	370	nC
Q_{ge}	Gate to Emitter Charge		-	28	42	nC
Q_{gc}	Gate to Collector Charge		-	129	195	nC

Electrical Characteristics of the Diode $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max	Units
V _{FM}	Diode Forward Voltage	I _F = 50 A	T _C = 25°C	-	1.75	2.1	V
			T _C = 175°C	-	1.35	-	
E _{rec}	Reverse Recovery Energy	I _F = 50 A, di _F /dt = 200 A/μs V _R =400 V	T _C = 175°C	-	0.14	-	mJ
t _{rr}	Diode Reverse Recovery Time		T _C = 25°C	-	41	55	ns
			T _C = 175°C	-	126	-	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	-	81	115	nC
			T _C = 175°C	-	736	-	

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

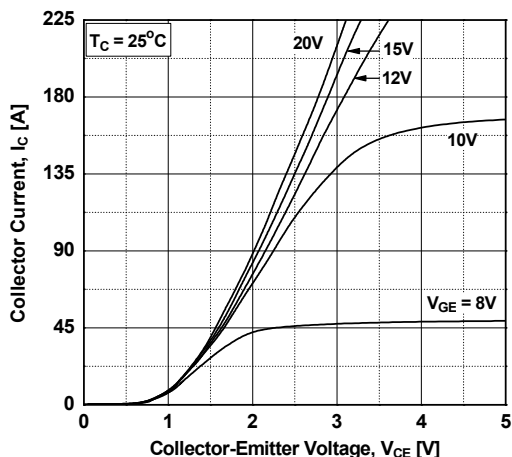


Figure 2. Typical Output Characteristics

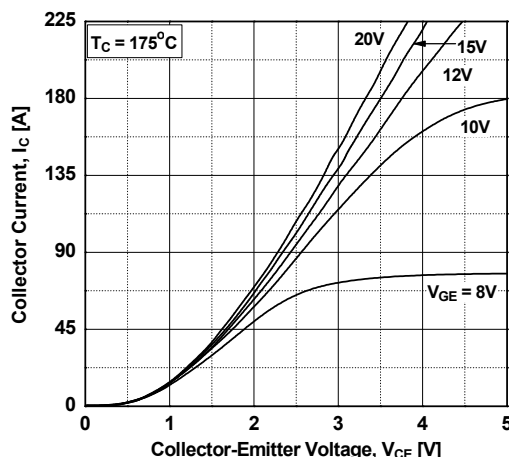


Figure 3. Typical Saturation Voltage Characteristics

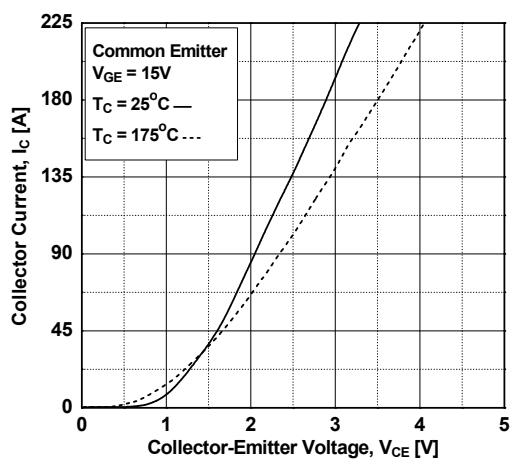


Figure 4. Transfer Characteristics

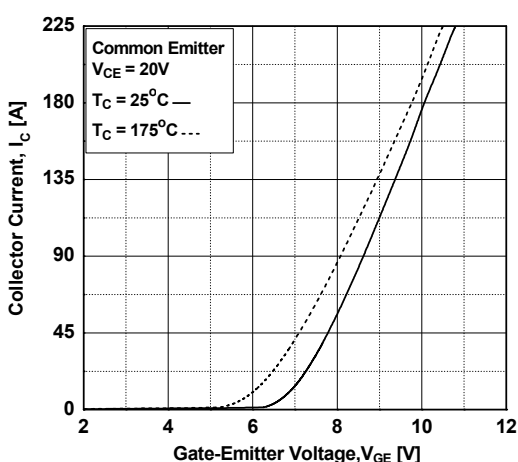


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

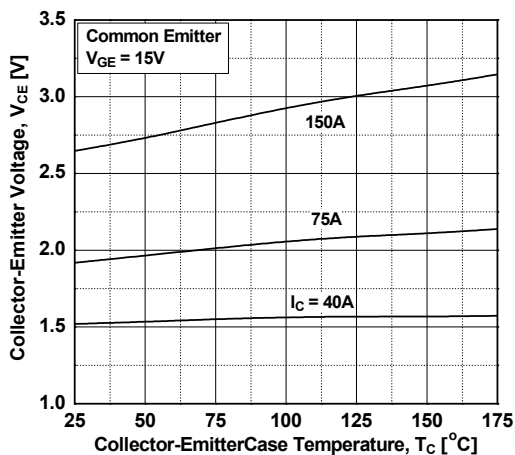
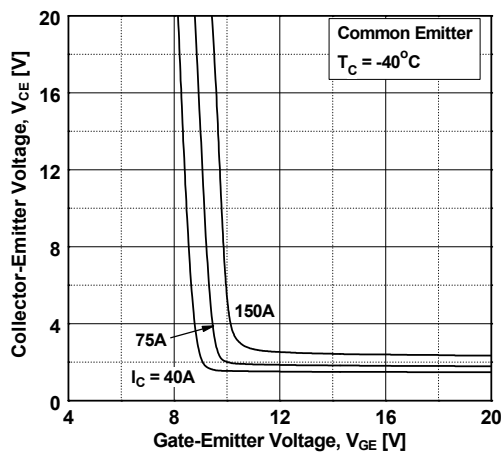


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

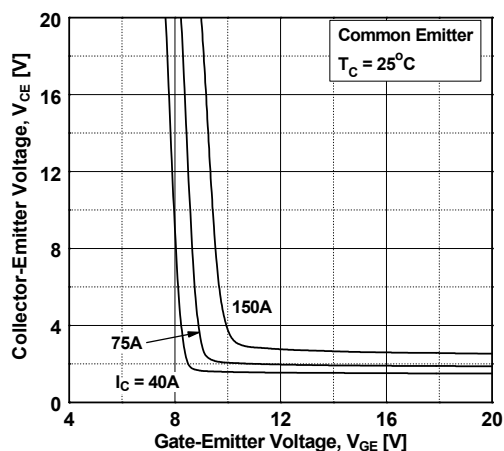


Figure 8. Saturation Voltage vs. V_{GE}

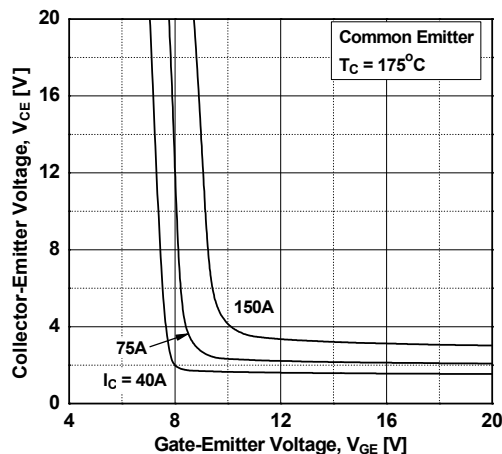


Figure 9. Capacitance Characteristics

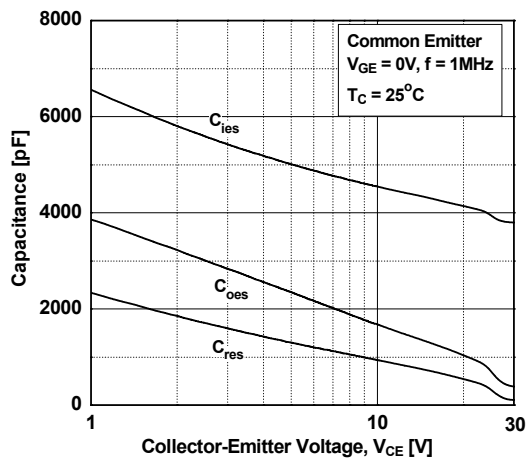


Figure 10. Gate charge Characteristics

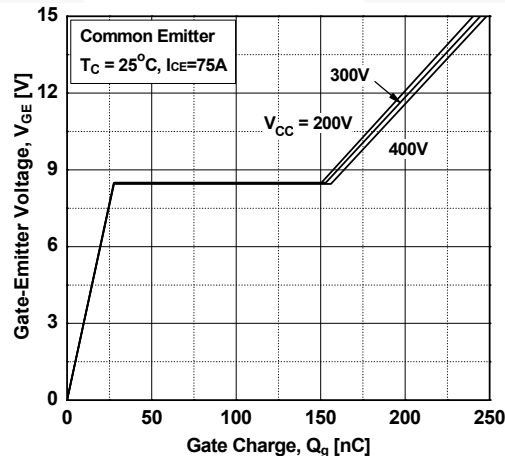


Figure 11. Turn-off Characteristics vs. Gate Resistance

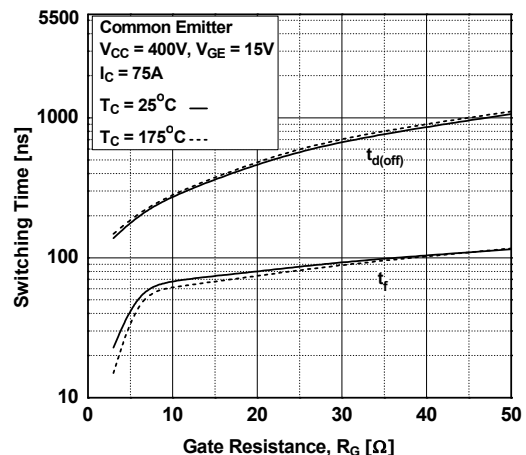
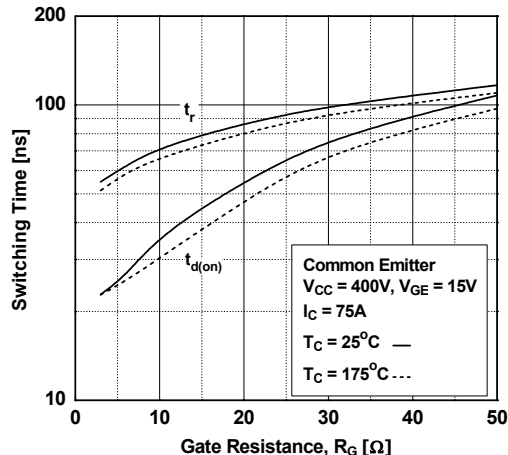


Figure 12. Turn-on Characteristics vs. Gate Resistance



Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

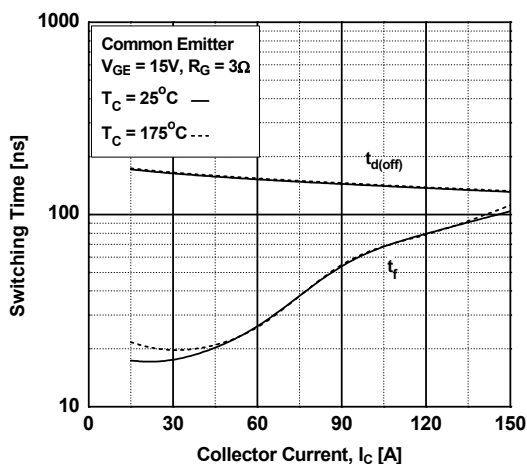


Figure 14. Turn-on Characteristics vs. Collector Current

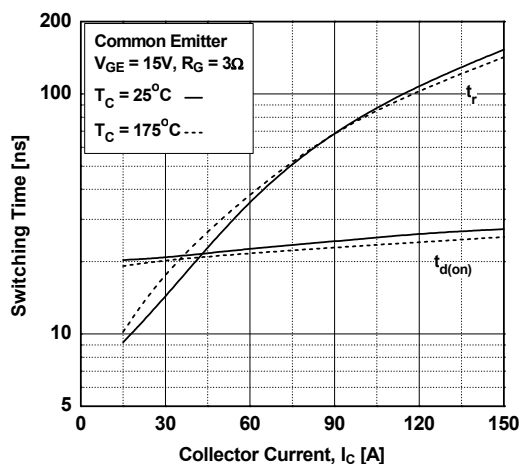


Figure 15. Switching Loss vs. Collector Current

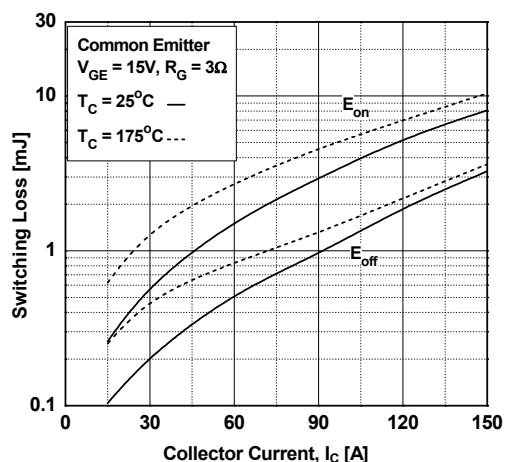


Figure 16. Switching Loss vs. Gate Resistance

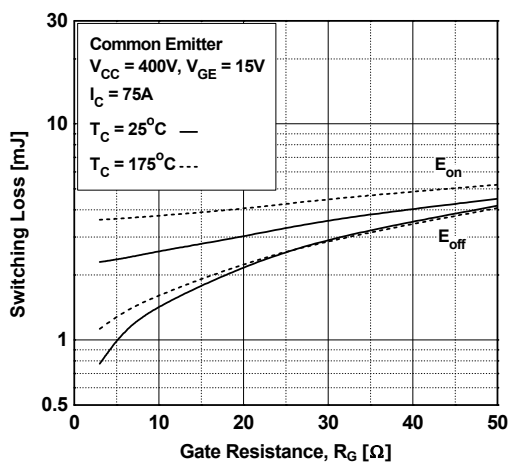


Figure 17. SOA Characteristics

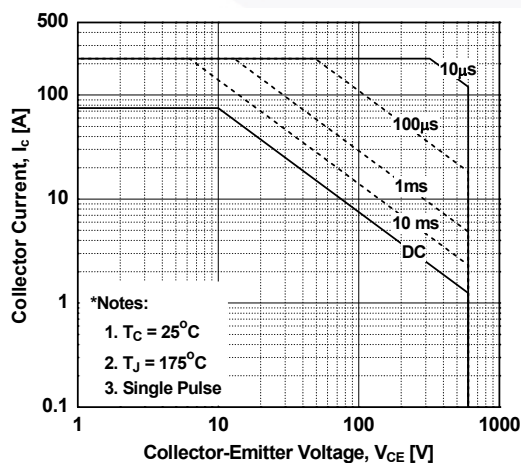
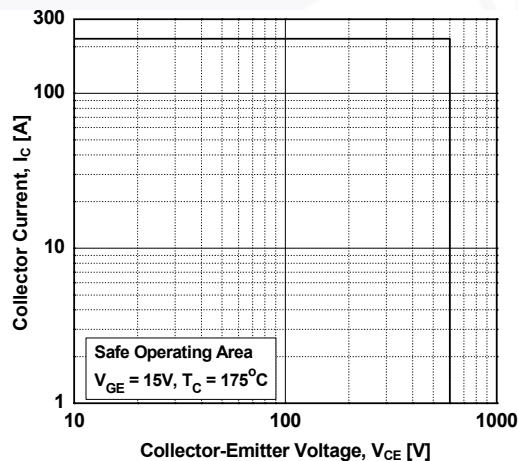


Figure 18. Turn off Switching SOA Characteristics



Typical Performance Characteristics

Figure 19. Current Derating

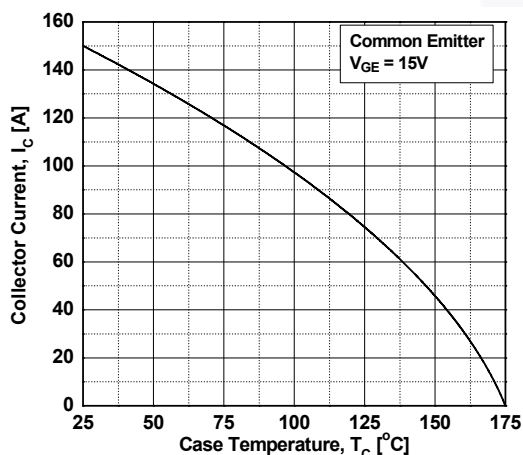


Figure 20. Load Current vs. Frequency

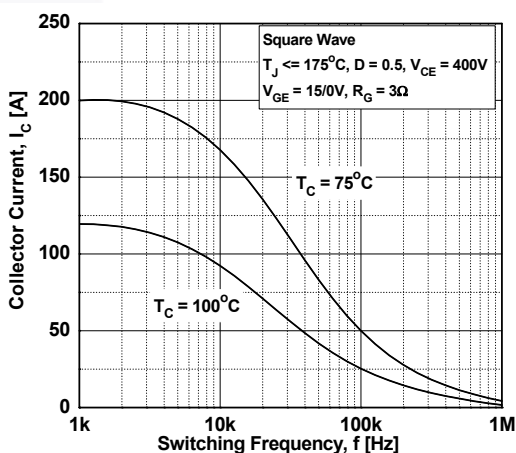


Figure 21. Forward Characteristics

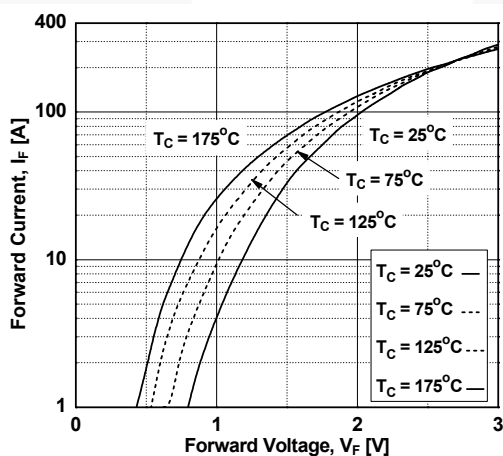


Figure 22. Reverse Current

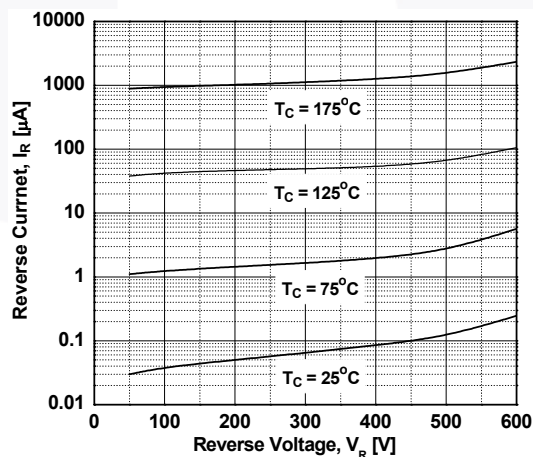


Figure 23. Stored Charge

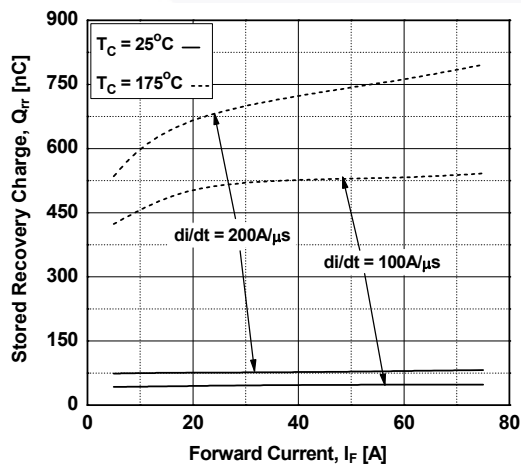
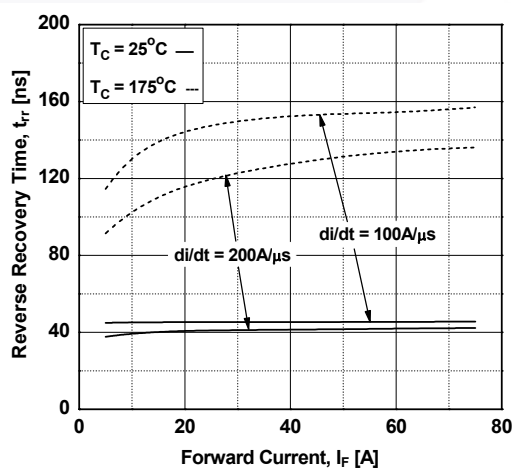


Figure 24. Reverse Recovery Current



Typical Performance Characteristics

Figure 25. Transient Thermal Impedance of IGBT

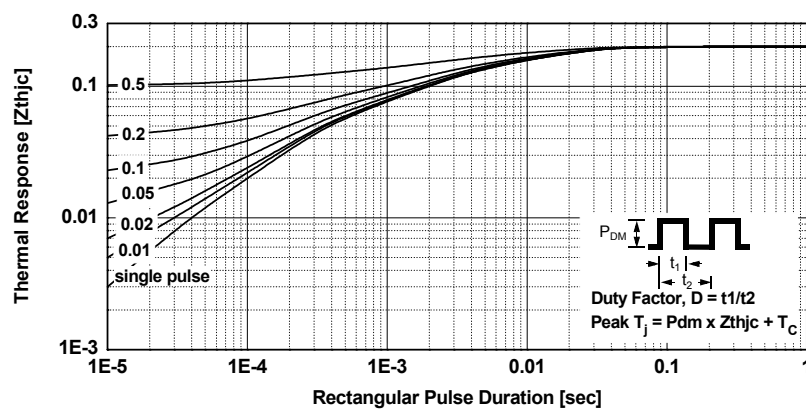
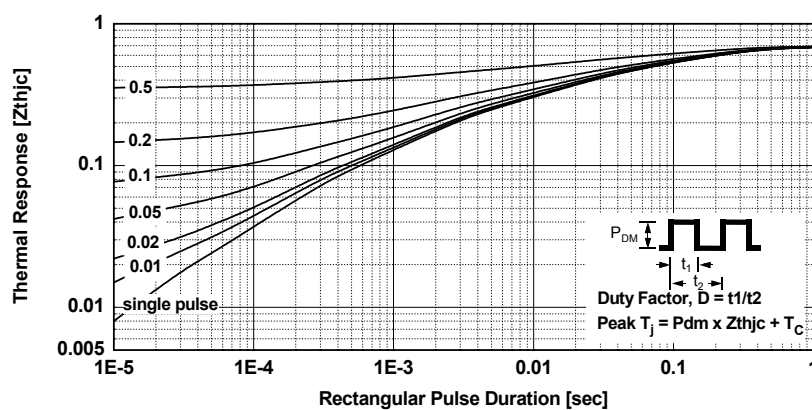
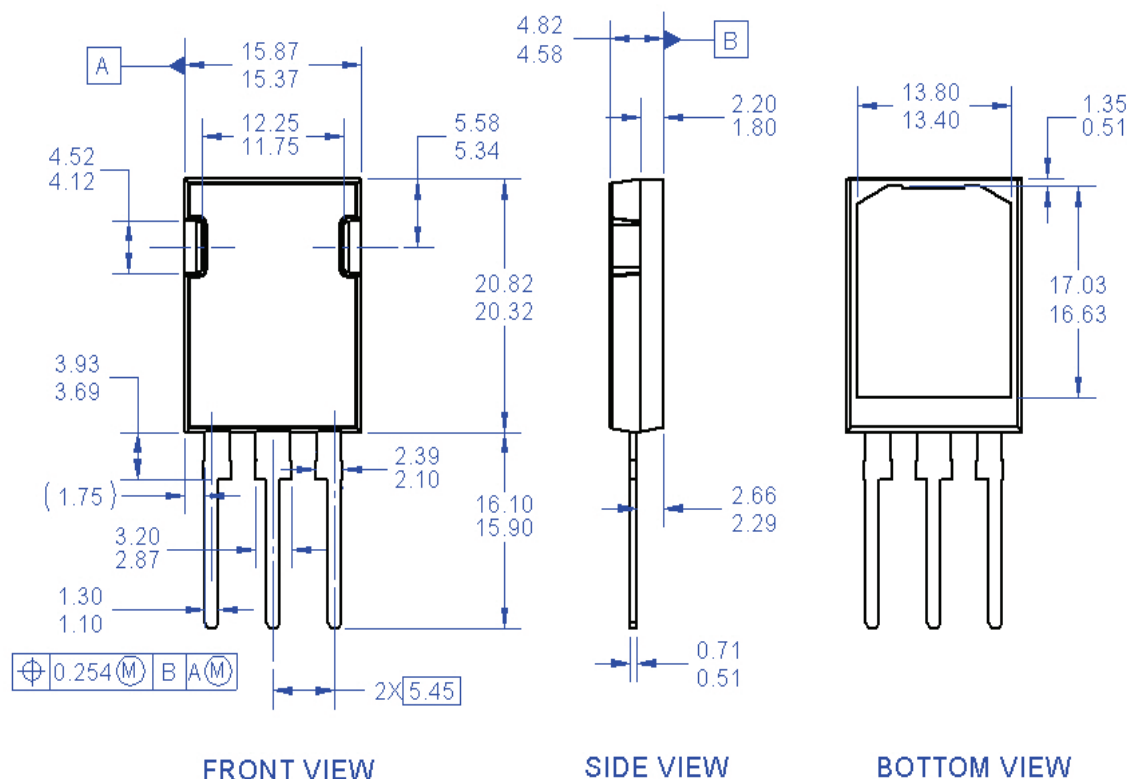


Figure 26. Transient Thermal Impedance of Diode



Mechanical dimensions



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- D. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- E. DRAWING FILE NAME: TO247D03REV3



Figure 27. TO-247 3L - 3LDS, POWER TO247, NON JEDEC

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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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